

**Radiation Hardened High Slew Rate Operational Amplifier**

The HS-2510RH is a radiation hardened high performance operational amplifier which set the standard for maximum slew rate and wide bandwidth operation in moderately powered, internally compensated, monolithic devices. In addition to excellent dynamic characteristics, this dielectrically isolated amplifier also offers low offset current and high input impedance.

The  $\pm 50V/ms$  minimum slew rate and fast settling time of the HS-2510RH are ideally suited for high speed D/A, A/D, and pulse amplification designs. The HS-2510RH superior bandwidth and 750kHz minimum full power bandwidth are extremely useful in RF and video applications. To insure compliance with slew rate and transient response specifications, all devices are 100% tested for AC performance characteristics over full temperature limits. To improve signal conditioning accuracy, the HS-2510RH provides a maximum offset current of 25nA and a minimum input impedance of 50M $\Omega$ , both at 25°C, as well as offset voltage trim capability.

**Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed here must be used when ordering.**

Detailed Electrical Specifications for these devices are contained in SMD 5962-95686. A "hot-link" is provided on our homepage for downloading. [www.intersil.com/spacedefense/space.asp](http://www.intersil.com/spacedefense/space.asp)

**Features**

- Electrically Screened to SMD # 5962-95686
- QML Qualified per MIL-PRF-38535 Requirements
- High Slew Rate. . . . . 50V/ $\mu s$  (Min), 65V/ $\mu s$  (Typ)
- Wide Power Bandwidth . . . . . 750kHz (Min)
- Low Offset Current . . . . . 25nA (Min), 10nA (Typ)
- High Input Impedance . . . . . 50M $\Omega$  (Min), 100M $\Omega$  (Typ)
- Wide Small Signal Bandwidth . . . . . 12MHz (Typ)
- Fast Settling Time (0.1% of 10V Step) . . . . . 250ns (Typ)
- Low Quiescent Supply Current. . . . . 6mA (Max)
- Internally Compensated For Unity Gain Stability
- Total Gamma Dose. . . . . 10kRAD(Si)

**Applications**

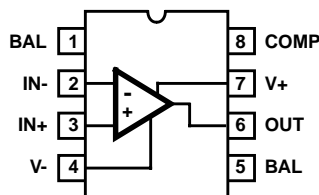
- Data Acquisition Systems
- RF Amplifiers
- Video Amplifiers
- Signal Generators
- Pulse Amplification

**Ordering Information**

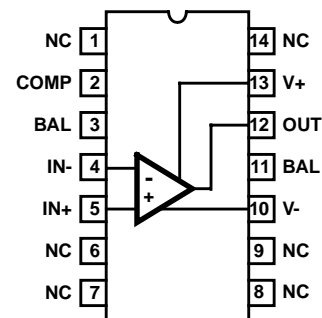
ORDERING NUMBER	INTERNAL MKT. NUMBER	TEMP. RANGE (°C)
5962D9568601VPA	HS7-2510RH-Q	-55 to 125
5962D9568601VPC	HS7B-2510RH-Q	-55 to 125
5962D9568601VXC	HS9-2510RH-Q	-55 to 125

**Pinouts**

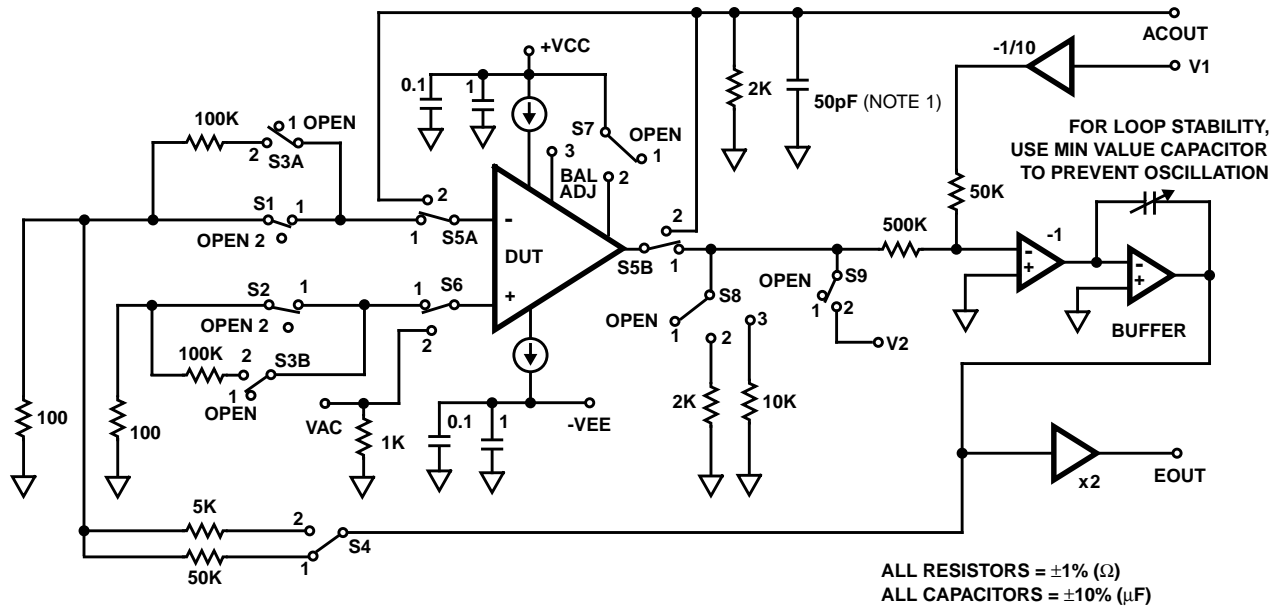
**HS-2510RH GDIP1-T8 (CERDIP)  
OR  
HS-2510RH CDIP2-T8 (SBDIP)  
TOP VIEW**



**HS-2510RH  
CDFP3-F14 (FLATPACK)  
TOP VIEW**



Test Circuit



NOTE:

- 1. Includes stray capacitances.

FIGURE 1. SIMPLIFIED TEST CIRCUIT

Test Circuit and Waveforms

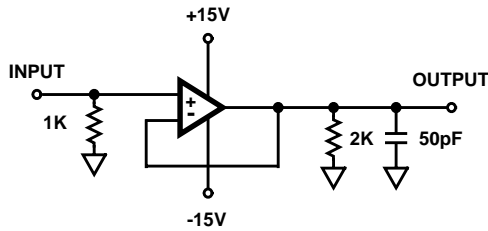
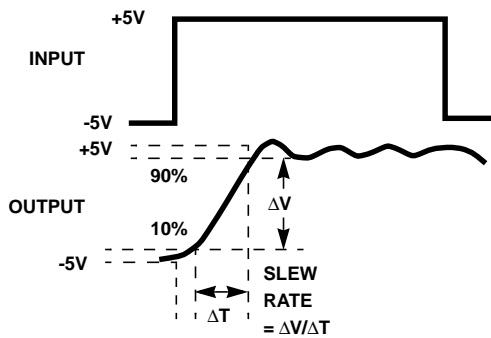
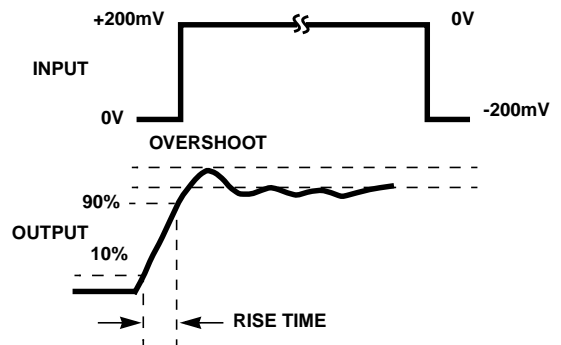


FIGURE 2. SIMPLIFIED TEST CIRCUIT



NOTE: Measured on both positive and negative transitions. Capacitance at Compensation pin should be minimized.

FIGURE 3. SLEW RATE WAVEFORM



NOTE: Measured on both positive and negative transitions. Capacitance at Compensation pin should be minimized.

FIGURE 4. TRANSIENT RESPONSE WAVEFORM

**Typical Performance Curves** Unless Otherwise Specified:  $T_A = 25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$

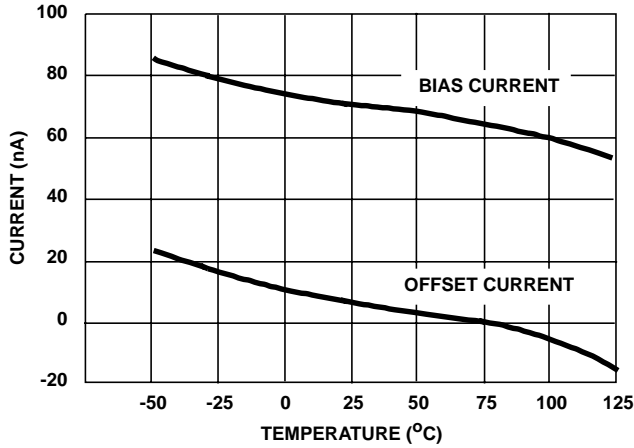


FIGURE 5. INPUT BIAS AND OFFSET CURRENT vs TEMPERATURE

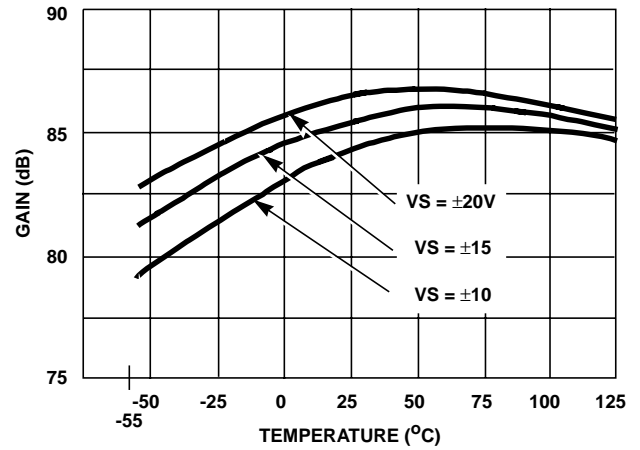


FIGURE 6. OPEN LOOP VOLTAGE GAIN vs TEMPERATURE

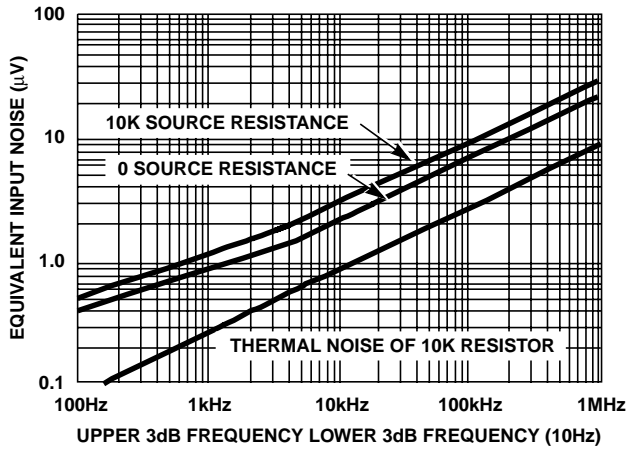


FIGURE 7. EQUIVALENT INPUT NOISE vs BANDWIDTH

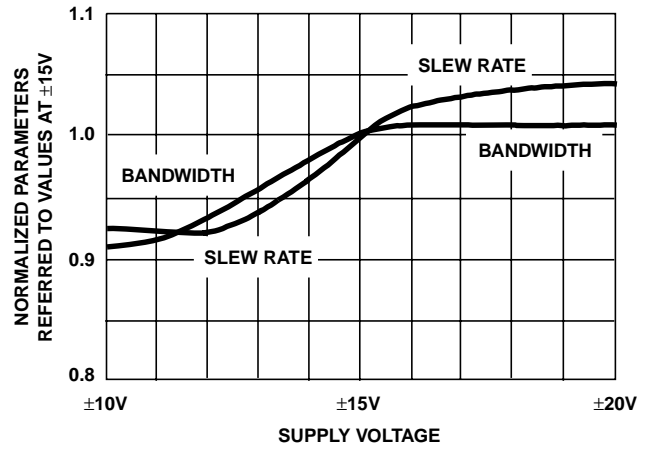


FIGURE 8. NORMALIZED AC PARAMETERS vs SUPPLY VOLTAGE AT  $25^\circ\text{C}$

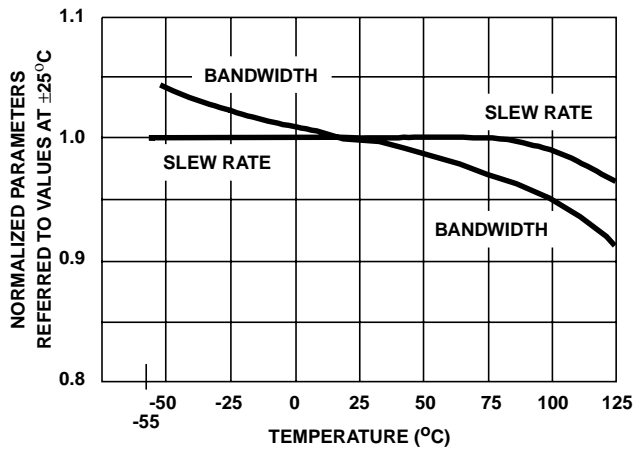


FIGURE 9. NORMALIZED AC PARAMETERS vs TEMPERATURE

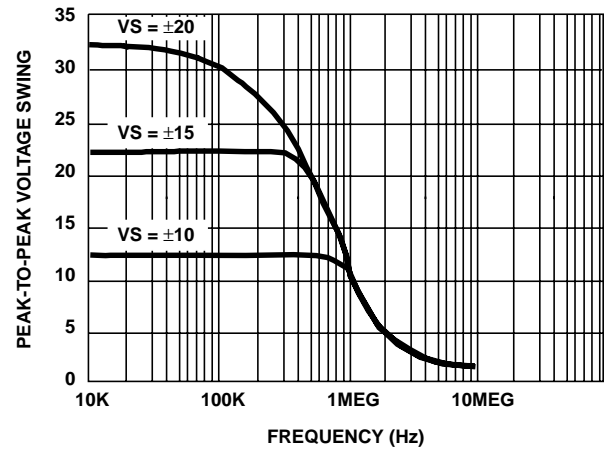
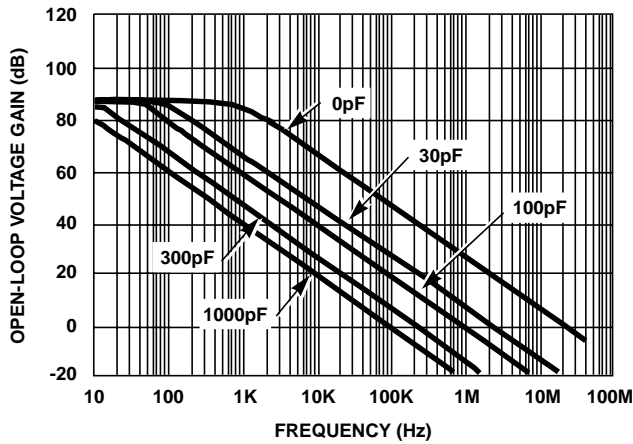


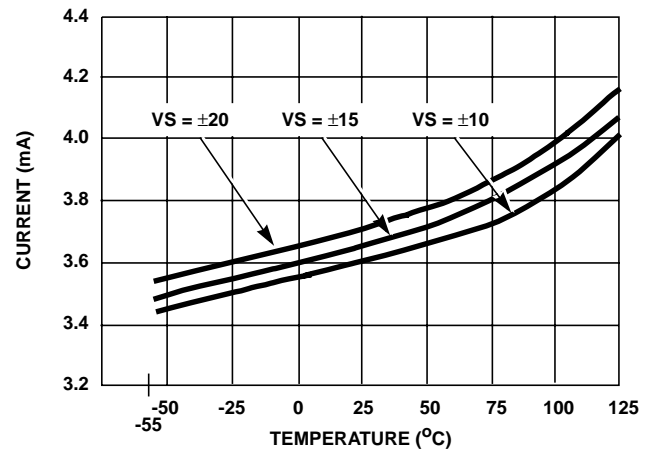
FIGURE 10. OUTPUT VOLTAGE SWING vs FREQUENCY AT  $25^\circ\text{C}$

**Typical Performance Curves** Unless Otherwise Specified:  $T_A = 25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$  (Continued)

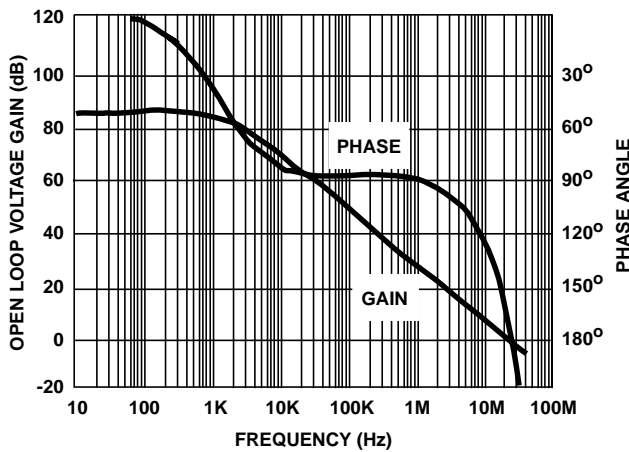


NOTE: External compensation components are not required for stability, but may be added to reduce bandwidth, if desired.

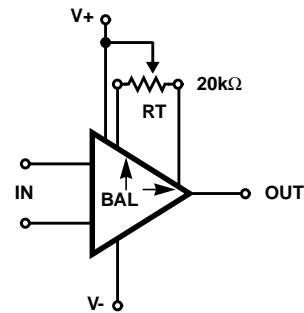
**FIGURE 11. OPEN LOOP FREQUENCY RESPONSE FOR VARIOUS VALUES OF CAPACITORS FROM COMPENSATION PIN TO GROUND**



**FIGURE 12. POWER SUPPLY CURRENT vs TEMPERATURE**

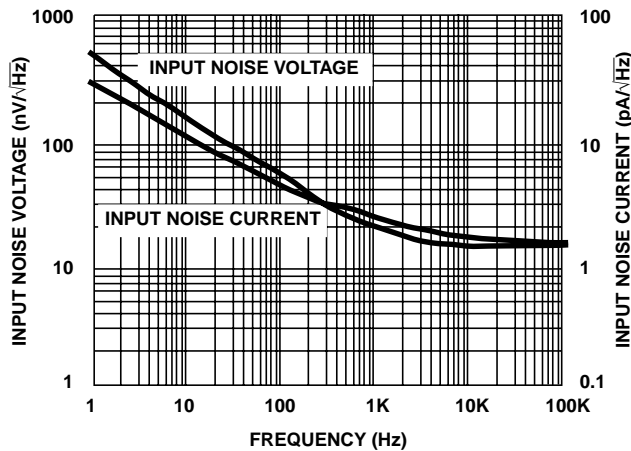


**FIGURE 13. OPEN LOOP GAIN AND PHASE RESPONSE vs FREQUENCY**



NOTE: Tested offset adjustment is  $|V_{OS} + 1\text{mV}|$  minimum referred to output typical range is  $\pm 8\text{mV}$  for  $R_T = 20\text{k}\Omega$ .

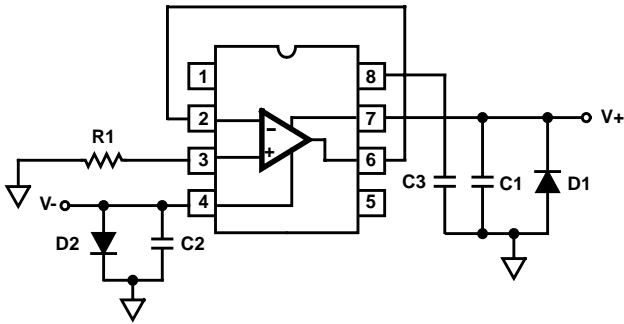
**FIGURE 14. SUGGESTED  $V_{OS}$  ADJUSTMENT**



**FIGURE 15. INPUT NOISE DENSITY vs FREQUENCY**

**Burn-In Circuits**

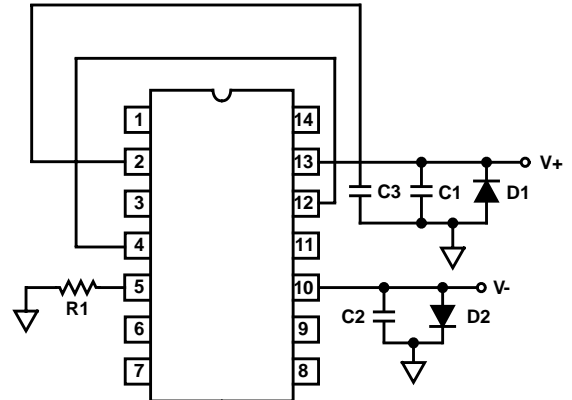
HS7-2510RH CERDIP



NOTES:

2. R1 = 1MΩ, ±5%, 1/4W (Min)
3. C1 = C2 = 0.01μF/Socket (Min) or 0.1μF/Row (Min)
4. C3 = 0.01μF/Socket (10%)
5. D1 = D2 = 1N4002 or Equivalent (Per Board)
6. |(V+) - (V-)| = 30V

HS9-2510RH CERAMIC FLATPACK

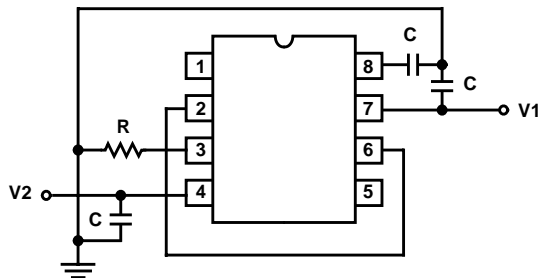


NOTES:

7. R1 = 1MΩ, ±5%, 1/4W (Min)
8. C1 = C2 = 0.01μF/Socket (Min) or 0.1μF/Row (Min)
9. C3 = 0.01μF/Socket (±10%)
10. D1 = D2 = 1N4002 or Equivalent (Per Board)
11. |(V+) - (V-)| = 31V ±1V

**Irradiation Circuit**

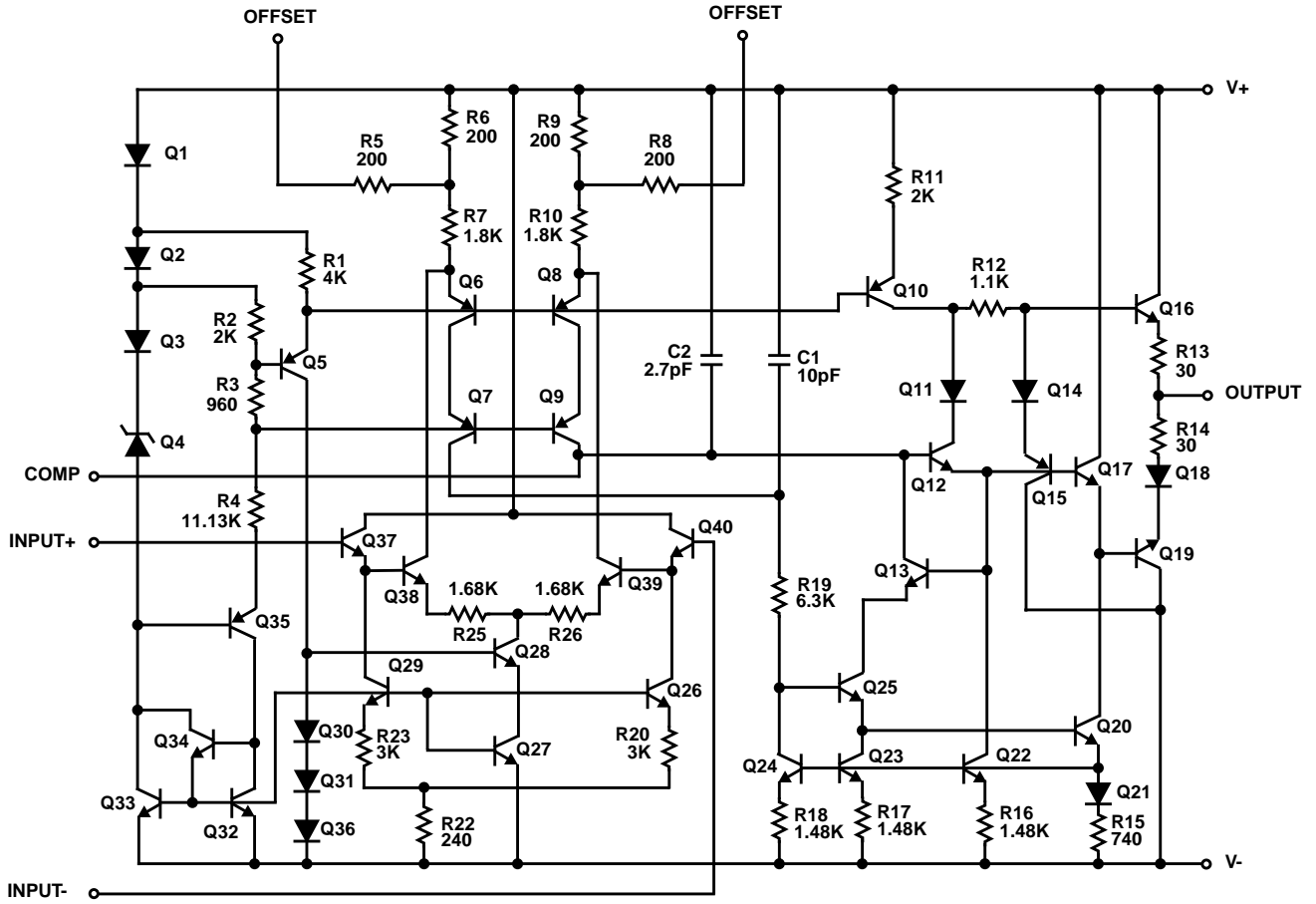
HS7-2510RH



NOTES:

12. V1 = +15V ±10%
13. V2 = -15V ±10%
14. R = 1MΩ ±5%
15. C = 0.1μF ±10%

Schematic Diagram



# HS-2510RH

## Die Characteristics

### DIE DIMENSIONS:

65 mils x 57 mils x 19 mils  
(1660 $\mu$ m x 1950 $\mu$ m x 483 $\mu$ m)

### INTERFACE MATERIALS:

#### Glassivation:

Type: Nitride  
Thickness: 7k $\text{\AA}$   $\pm$ 0.7k $\text{\AA}$

#### Top Metallization:

Type: Aluminum  
Thickness: 16k $\text{\AA}$   $\pm$ 2k $\text{\AA}$

#### Substrate:

Linear Bipolar, DI

### Backside Finish:

Silicon

### ASSEMBLY RELATED INFORMATION:

#### Substrate Potential (Powered Up):

Unbiased

### ADDITIONAL INFORMATION:

#### Worst Case Current Density:

$<2 \times 10^5 \text{A/cm}^2$

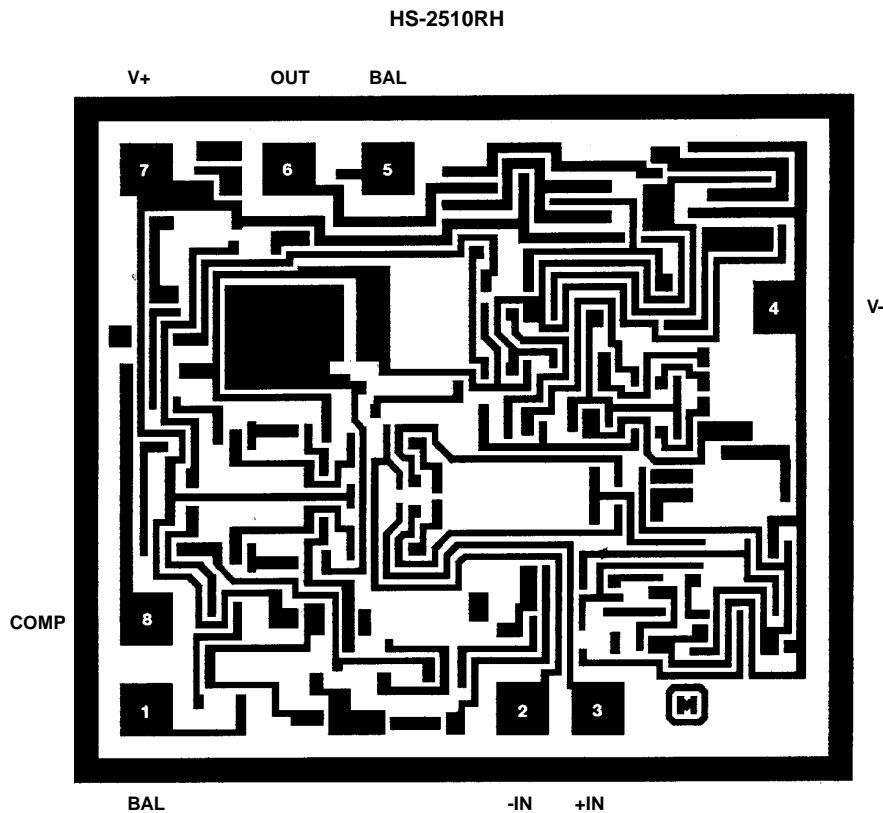
#### Transistor Count:

40

#### Die Attach:

Temperature: CERDIP 460 $^{\circ}$ C (Max)

## Metallization Mask Layout



All Intersil semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

*Intersil semiconductor products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.*

For information regarding Intersil Corporation and its products, see web site <http://www.intersil.com>